

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT(S): Hiroyuki Yoshida, et al. ATTY. DOCKET NO. 09792909-6113
SERIAL NO. 10/524,749 GROUP ART UNIT: 2814
FILING DATE: February 15, 2005 Examiner: Abul Kalam
INVENTION: “INSULATED GATE FIELD EFFECT TRANSISTOR AND
METHOD OF MANUFACTURING SAME, AND IMAGE PICKUP
DEVICE AND METHOD OF MANUFACTURING SAME”

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

AMENDMENT “C” AFTER FINAL

S I R:

This Amendment “C” After Final is filed in response to the final Office Action of November 3, 2006. Please reconsider the application in view of the remarks presented below.